

# BTA24, BTB24, BTA25 BTA26, BTB26, T25

### 25 A standard and Snubberless™ triacs

#### **Features**

- High current triac
- Low thermal resistance with clip bonding
- High commutation (4 quadrant) or very high commutation (3 quadrant) capability
- BTA series UL1557 certified (File ref: 81734)
- Packages are RoHS (2002/95/EC) compliant

### **Applications**

Applications include the ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits, etc., or for phase control operation in light dimmers, motor speed controllers, and silmilar.

The snubberless versions (BTA/BTB...W and T25 series) are especially recommended for use on inductive loads, due to their high commutation performances. The BTA series provides an insulated tab (rated at 2500  $V_{\rm RMS}$ ).

### **Description**

Available either in through-hole or surface-mount packages, the **BTA24**, **BTB24**, **BTA25**, **BTA26**, **BTB26** and **T25** triac series is suitable for general purpose mains power AC switching.

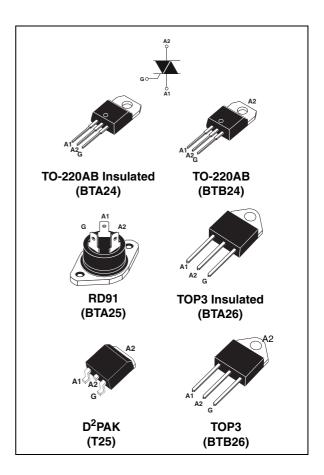


Table 1. Device summary

Symbol	Parameter	BTA24 <sup>(1)</sup>	BTB24	BTA25 <sup>(1)</sup>	BTA26 <sup>(1)</sup>	BTB26	T25	Unit
I <sub>T(RMS)</sub>	RMS on-state current	25	25	25	25	25	25	Α
V <sub>DRM</sub> /V <sub>RRM</sub>	Repetitive peak off-state voltage	600 / 800	600 / 800	600 / 800	600 <sup>(2)</sup> / 800	600	600 / 800	٧
I <sub>GT</sub> (Snubberless)	Triggering gate current	35 / 50	35 / 50	50	35 / 50	-	35	mA
I <sub>GT</sub> (Standard)	Triggering gate current	-	50	50	50	50	-	mA

<sup>1.</sup> Insulated packages

TM: Snubberless is a trademark of STMicroelectronics

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<sup>2. 600</sup> V version available only with  $I_{GT} = 50$  mA (Snubberless and Standard)

## 1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parame		Value	Unit	
		TOP3	T <sub>c</sub> = 105° C		
	RMS on-state current (full sine wave)	D <sup>2</sup> PAK / TO-220AB	T <sub>c</sub> = 100° C	25	Δ.
I <sub>T(RMS)</sub>		RD91 Ins/ TOP3 Ins.	T <sub>c</sub> = 100° C	25	A
		TO-220AB Ins.	T <sub>c</sub> = 75° C		
	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	250	Α
I <sub>TSM</sub>	current (full cycle, $T_j$ initial = 25° C)	F = 60 Hz	t = 16.7 ms	260	A
l <sup>2</sup> t	$I^2$ t Value for fusing $t_p = 10 \text{ ms}$			340	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz	T <sub>j</sub> = 125° C	50	A/μs
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltage	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25° C	V <sub>DRM</sub> /V <sub>RRM</sub> + 100	V
I <sub>GM</sub>	Peak gate current $t_p = 20 \mu s$ $T_j = 125^{\circ} C$		T <sub>j</sub> = 125° C	4	Α
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 125^{\circ} C$			1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	° C

Table 3. Electrical characteristics ( $T_j = 25^{\circ}$  C, unless otherwise specified), Snubberless and logic level (3 quadrants) T25, BTA/BTB24...W, BTA25...W, BTA26...W

Cumbal	Test Conditions	Quadrant		T25	BTA/BTB		Unit
Symbol	rest Conditions	Quaurant		T2535	CW	BW	Oilit
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V } R_L = 33 \Omega$	I - II - III	MAX.	35	35	50	mA
V <sub>GT</sub>	AD = 15 A UL = 22.75	1 - 11 - 111	MAX.		1.3		٧
V <sub>GD</sub>	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 125^{\circ} \text{ C}$	1 - 11 - 111	MIN.		0.2		٧
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 500 mA		MAX.	50	50	75	mA
IL	I <sub>G</sub> = 1.2 I <sub>GT</sub>	I - III	MAX.	70	70	80	mA
'L	IG - 1.2 IGT	II	IVIAA.	80	80	100	ША
dV/dt (2)	V <sub>D</sub> = 67 %V <sub>DRM</sub> gate open	T <sub>j</sub> = 125° C	MIN.	500	500	1000	V/µs
(dl/dt)c (2)	Without snubber	T <sub>j</sub> = 125° C	MIN.	13	13	22	A/ms

<sup>1.</sup> minimum  $I_{\mbox{\scriptsize GT}}$  is guaranted at 5% of  $I_{\mbox{\scriptsize GT}}$  max.

<sup>2.</sup> for both polarities of A2 referenced to A1.

Table 4. Electrical characteristics (T<sub>j</sub> = 25° C, unless otherwise specified), standard (4 quadrants), BTB24...B, BTA25...B, BTA26...B, BTB26...B

Symbol	Test Conditions	Quadrant		Value	Unit
I <sub>GT</sub> <sup>(1)</sup>		1 - 11 - 111	MAX.	50	mA
'GT`	$V_D = 12 \text{ V}$ $R_L = 33 \Omega$	IV	IVIAA.	100	IIIA
V <sub>GT</sub>		ALL	MAX.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 125^{\circ} \text{ C}$	ALL	MIN.	0.2	V
I <sub>H</sub> <sup>(2)</sup> )	I <sub>T</sub> = 500 mA		MAX.	80	mA
	I <sub>G</sub> = 1.2 I <sub>GT</sub>	I - III - IV	MAX.	70	mA
IL	IG = 1.2 IGT	II	IVIAA.	160	IIIA
dV/dt <sup>(2)</sup>	V <sub>D</sub> = 67 %V <sub>DRM</sub> gate open	T <sub>j</sub> = 125° C	MIN.	500	V/µs
(dV/dt)c (2)	(dl/dt)c = 13.3 A/ms	T <sub>j</sub> = 125° C	MIN.	10	V/µs

<sup>1.</sup> minimum  $I_{\mbox{\scriptsize GT}}$  is guaranted at 5% of  $I_{\mbox{\scriptsize GT}}$  max.

Table 5. Static characteristics

Symbol	Test	Value	Unit		
V <sub>TM</sub> <sup>(1)</sup>	$I_{TM} = 35 \text{ A}$ $t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25° C	MAX.	1.55	V
V <sub>t0</sub> (1)	Threshold voltage	T <sub>j</sub> = 125° C	MAX.	0.85	V
R <sub>d</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 125° C	MAX.	16	mΩ
I <sub>DRM</sub>	V -V	T <sub>j</sub> = 25° C	MAX.	5	μA
I <sub>RRM</sub>	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 125° C	IVIAA.	3	mA

<sup>1.</sup> for both polarities of A2 referenced to A1.

Table 6. Thermal resistance

Symbol	Parameter			Value	Unit
			TOP 3	0.6	
Б	lunation to social (AC)		D <sup>2</sup> PAK / TO-220AB	0.8	0 0 1 1 1
H <sub>th(j-c)</sub>	R <sub>th(j-c)</sub> Junction to case (AC)		RD91 Insulated / TOP3 Insulated	0.9	° C/W
			TO-220AB Insulated	1.7	
		$^{(1)}S = 1 \text{ cm}^2$	D <sup>2</sup> PAK	45	
R <sub>th(j-a)</sub> Junction to a	Junction to ambient		TOP3 / TOP3 Insulated	50	° C/W
			TO-220AB / TO-220AB Insulated	60	

<sup>1.</sup> S = Copper surface under tab.

<sup>2.</sup> for both polarities of A2 referenced to A1.

Surge peak on-state current

Figure 1. Maximum power dissipation versus Figure 2. RMS on-state current versus case RMS on-state current (full cycle) temperature (full cycle)

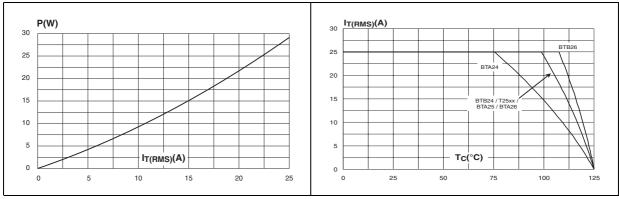


Figure 3. D<sup>2</sup>PAK RMS on-state current versus Figure 4. Relative variation of thermal ambient temperature (printed impedance versus pulse circuit board FR4, copper duration

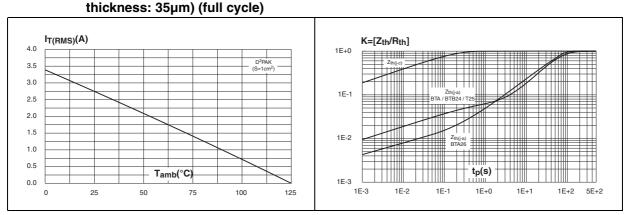


Figure 5. On-state characteristics (maximum values)

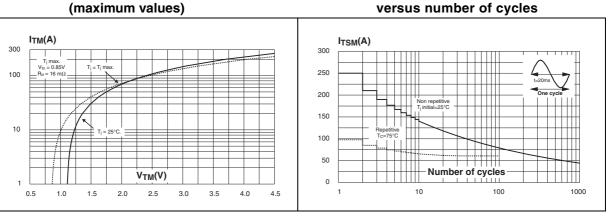
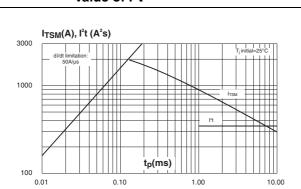


Figure 6.

Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10$  ms and corresponding value of l<sup>2</sup>t



Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

Figure 8.

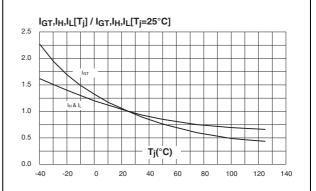
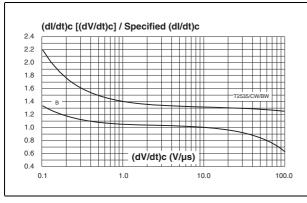
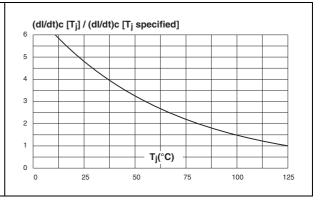


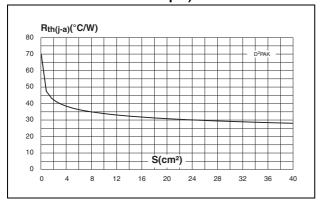
Figure 9. decrease of main current versus (dV/dt)c (typical values)

Relative variation of critical rate of Figure 10. Relative variation of critical rate of decrease of main current versus Ti





D<sup>2</sup>PAK thermal resistance junction to Figure 11. ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 µm)



## 2 Ordering information scheme

Figure 12. BTA and BTB series

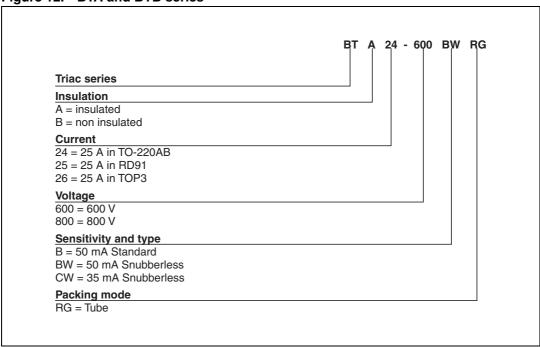
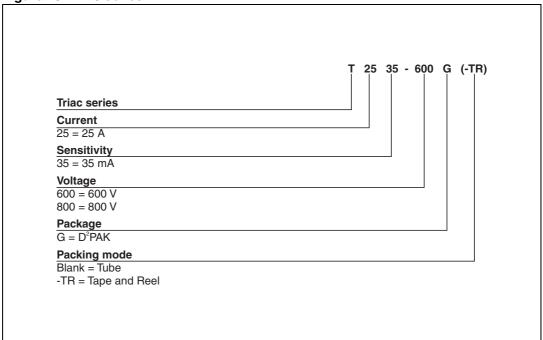


Figure 13. T25 series



## 3 Package information

- Epoxy meets UL94,V0
- Cooling method: C
- Recommended torque value: 0.4 0.5 Nm (TO-220AB), 0.9 1.2 Nm (TOP3 and RD91)
- Maximum torque value for BTB24 is 0.5 Nm

Table 7. D<sup>2</sup>PAK dimensions

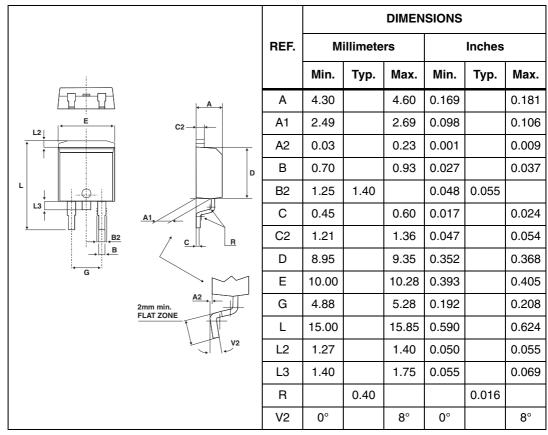


Figure 14. D<sup>2</sup>PAK footprint dimensions (in millimeters)

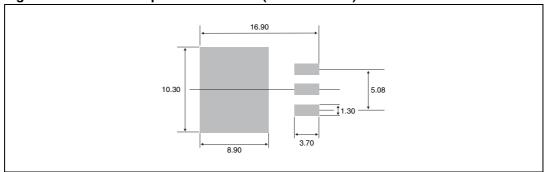
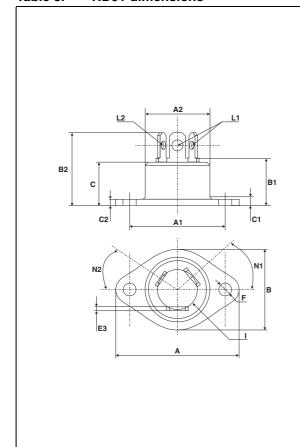


Table 8. RD91 dimensions



		DIMEN	ISIONS	
REF.	Millim	neters	Incl	hes
	Min.	Max.	Min.	Max.
Α		40.00		1.575
A1	29.90	30.30	1.177	1.193
A2		22.00		0.867
В		27.00		1.063
B1	13.50	16.50	0.531	0.650
B2		24.00		0.945
С		14.00		0.551
C1		3.50		0.138
C2	1.95	3.00	0.077	0.118
E3	0.70	0.90	0.027	0.035
F	4.00	4.50	0.157	0.177
I	11.20	13.60	0.441	0.535
L1	3.10	3.50	0.122	0.138
L2	1.70	1.90	0.067	0.075
N1	33°	43°	33°	43°
N2	28°	38°	28°	38°

**DIMENSIONS** REF. Millimeters Inches Min. Тур. Max. Min. Тур. Max. 4.4 4.6 0.173 0.181 Α В 1.45 0.057 0.061 1.55 С 14.35 15.60 0.565 0.614 D 0.5 0.028 0.7 0.020 Ε 2.9 0.106 0.114 2.7 0.650 F 15.8 16.5 0.622 G 20.4 21.1 0.815 0.831 Н 15.1 15.5 0.594 0.610 J 5.4 5.65 0.213 0.222 Κ 3.4 0.144 3.65 0.134 ØL 4.08 4.17 0.161 0.164 Ρ 1.20 1.40 0.047 0.055 0.181 R 4.60

Table 9. TOP3 (insulated and non\_insulated) dimensions

**DIMENSIONS** Millimeters REF. **Inches** Min. Тур. Max. Min. Тур. Max. 15.20 15.90 0.598 0.625 Α 3.75 0.147 a1 13.00 14.00 0.511 0.551 a2 10.00 В 10.40 0.393 0.409 0.88 0.024 0.034 b1 0.61 b2 1.23 1.32 0.048 0.051 С 4.40 4.60 0.173 0.181 c2 0.49 0.70 0.019 0.027 с1 2.72 0.094 0.107 c2 2.40 a2 2.40 2.70 0.094 0.106 е F 6.60 0.244 0.259 6.20 ØI 3.75 3.85 0.147 0.151 14 15.80 16.40 16.80 0.622 0.646 0.661 L 2.65 2.95 0.104 0.116 12 1.14 1.70 0.044 0.066 13 1.14 1.70 0.044 0.066 Μ 2.60 0.102

Table 10. TO-220AB (insulated and non-insulated) dimensions

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

# 4 Ordering information

Table 11. Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA/BTB24-xxxyzRG	BTA/BTB24 xxxyz	TO-220AB	2.3 g	50	Tube
BTA25-xxxyz	BTA25xxxyz	RD91	20 g	25	Bulk
BTA26-xxxyRG	BTA26xxxyz	TOP3 Ins.	4.5 g	30	Tube
BTB26-600BRG	BTB26600B	TOP3	4.5 g	30	Tube
T2535-xxxG	T2535 xxxG	D <sup>2</sup> PAK	1.5 g	50	Tube
T2535-xxxG-TR	T2535 xxxG	DIAN	1.5 g	1000	Tape and reel

**Note:** xxx = voltage, y = sensitivity, z = type

# 5 Revision history

Table 12. Revision history

Date	Revision	Description of changes
Oct-2002	6A	Previous update.
13-Feb-2006	7	TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added.
31-May-2006	8	Reformatted to current standard. $T_c$ in figure 3 changed to $T_{amb}$
31-Jul-2006	9	Typing error corrected on page 1 (BTB124 instead of BTB24)
05-Jul-2007	10	Added BTB26-600BRG. Restructured cover page and section <i>2:</i> Ordering information scheme on page 6 to simplify product selection. Thermal resistance values updated in <i>Table 6</i> and <i>Figure 2</i> . Graphic for I <sup>2</sup> t updated in <i>Figure 7</i> .

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